ENHANCED HIGH-SIDE CURRENT MONITOR

DESCRIPTION

The ZXCT1010 is a high side current sense monitor. Using this device eliminates the need to disrupt the ground plane when sensing a load current.

It is an enhanced version of the ZXCT1009 offering reduced typical output offset and improved accuracy at low sense voltage.

The wide input voltage range of 20V down to as low as 2.5V make it suitable for a range of applications. A minimum operating current of just 4 μ A, combined with its SOT23-5 package make suitable for portable battery equipment.

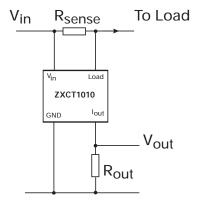
FEATURES

- Low cost, accurate high-side current sensing.
- Output voltage scaling.
- Up to 2.5V sense voltage.
- 2.5V 20V supply range.
- 300nA typical offset current.
- 3.5µA quiescent current.
- 1% typical accuracy.
- SOT23 -5 package.

APPLICATIONS

- Battery Chargers
- Smart Battery Packs
- DC Motor control
- Over current monitor
- Power Management
- Programmable current source

APPLICATION CIRCUIT



ORDERING INFORMATION

DEVICE	REEL	TAPE	QUANTITY PER
	SIZE	WIDTH	REEL
ZXCT1010E5TA	7″	8mm	3,000 units

PARTMARK 101

PACKAGE SOT23-5



ABSOLUTE MAXIMUM RATINGS

Voltage on any pin	-0.6V to 20V (relative to GND)
Continuous output current	25mA
Continuous sense voltage	$V_{in} + 0.5V > V_{sense}^{\dagger} > V_{in} - 5V$
Operating Temperature	-40 to 85°C
Storage Temperature	-55 to 150°C
Package Power Dissipation	(T _A = 25°C)
SOT23-5	500mW

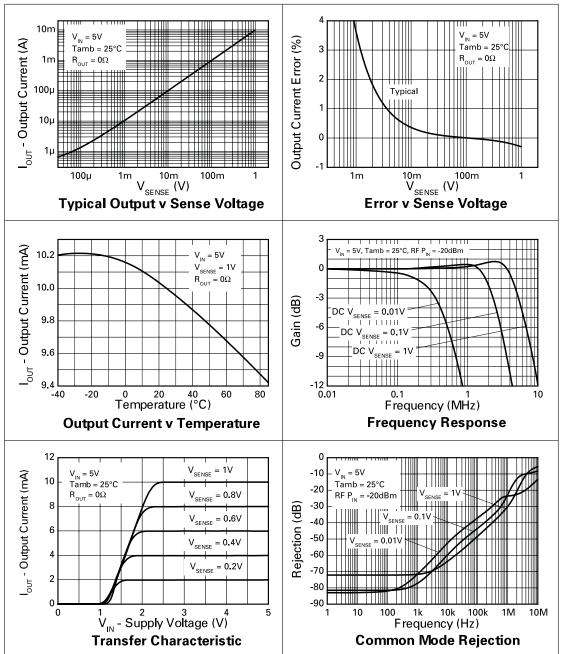
ELECTRICAL CHARACTERISTICS

Test Conditions T_A = 25°C, V_{in} = 5V, R_{out} = 100 $\Omega.$

SYMBOL	PARAMETER	CONDITIONS	LIMITS			UNIT
			Min	Тур	Max	
V _{in}	V _{CC} Range		2.5		20	V
I _{out} 1	Output current	V _{sense} = 0V	0	0.3	10	μA
		V _{sense} = 10mV	85	100	115	μA
		V _{sense} = 100mV	0.975	1.00	1.025	mA
		$V_{sense} = 200 mV$	1.95	2.00	2.05	mA
		V _{sense} = 1V	9.7	10.0	10.3	mA
lq	Ground pin current	V _{sense} = 0V		3.5	8	μA
V _{sense} ²	Sense Voltage		0		2500	mV
I _{sense}	Load pin				100	nA
	input current					
Acc	Accuracy	$R_{sense} = 0.1\Omega$				
		V _{sense} = 200mV	-2.5		2.5	%
Gm	Transconductance,			10000		μA/V
	I _{out} / V _{sense}					
BW	Bandwidth	RF P _{in} = -20dBm ³ V _{sense} = 10mV dc		300		kHz
		V _{sense} = 100mV dc		2		MHz

 1 Includes input offset voltage contribution $^{2}V_{sense}=V_{in}-V_{load}$ 3 -20dBm=63mVp-p into 50 Ω





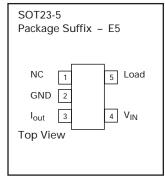
TYPICAL CHARACTERISTICS



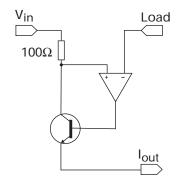
PIN DESCRIPTION

Pin Name	Pin Function
V _{in}	Supply Voltage
Load	Connection to load/battery
l _{out}	Output current, proportional to $V_{\text{in}}\text{-}V_{\text{load}}$
GND	Ground

CONNECTION DIAGRAM



SCHEMATIC DIAGRAM





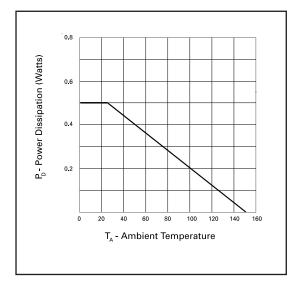
POWER DISSIPATION

The maximum allowable power dissipation of the device for normal operation (Pmax), is a function of the package junction to ambient thermal resistance (θ ja), maximum junction temperature (Tjmax), and ambient temperature (Tamb), according to the expression:

 $P_{max} = (Tj_{max} - T_{amb}) / \theta_{ja}$

The device power dissipation, P_D is given by the expression:

PD=Iout.(Vin-Vout) Watts



APPLICATIONS INFORMATION

The following lines describe how to scale a load current to an output voltage.

E.g.

A 1A current is to be represented by a 100mV output voltage:

1)Choose the value of R_{sense} to give 50mV > V_{sense} > 500mV at full load.

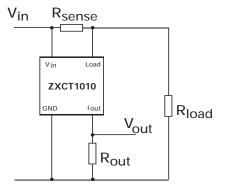
For example V_{sense} = 100mV at 1.0A. R_{sense} = 0.1/1.0 => 0.1 ohms.

2)Choose R_{out} to give V_{out} = 100mV, when V_{sense} = 100mV.

Rearranging ¹ for R_{out} gives: $R_{out} = V_{out} / (V_{sense} \times 0.01)$

 $R_{out} = 0.1 / (0.1 \times 0.01) = 100 \Omega$

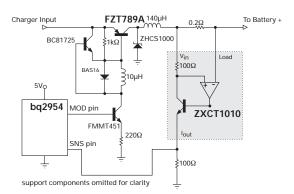
TYPICAL CIRCUIT APPLICATION



Where R_{load} represents any load including DC motors, a charging battery or further circuitry that requires monitoring, R_{sense} can be selected on specific requirements of accuracy, size and power rating.



Li-Ion Charger Circuit



The above figure shows the ZXCT1010 supporting the Benchmarq bq2954 Charge Management IC.

Most of the support components for the bg2954 are

omitted for clarity. This design also uses the Zetex

FZT789A high current Super-β PNP as the switching

transistor in the DC-DC step down converter and the

FMMT451 as the drive NPN for the FZT789A. The

circuit can be configured to charge up to four Li-Ion

cells at a charge current of 1.25A. Charge can be

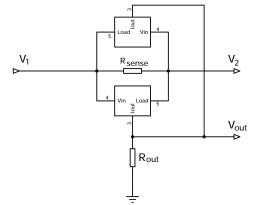
terminated on maximum voltage, selectable

minimum current, or maximum time out. Switching frequency of the PWM loop is approximately 120kHz.

APPLICATIONS INFORMATION (Continued)

Bi-Directional Current Sensing

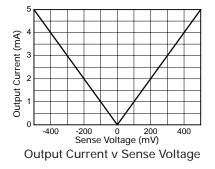
The ZXCT1010 can be used to measure current bi-directionally, if two devices are connected as shown below.



If the voltage V1 is positive with respect to the voltage V2 the lower device will be active, delivering a proportional output current to Rout. Due to the polarity of the voltage across Rsense, the upper device will be inactive and will not contribute to the current delivered to Rout. When V2 is more positive than V1, current will be flowing in the opposite direction, causing the upper device to be active instead.

Non-linearity will be apparent at small values of Vsense due to offset current contribution. Devices can use separate output resistors if the current direction is to be monitored independently.

Bi-directional Transfer Function



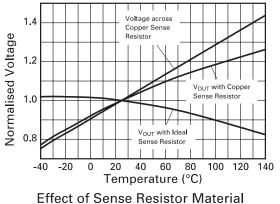


APPLICATIONS INFORMATION (Continued)

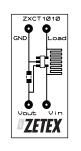
PCB trace shunt resistor for low cost solution.

The figure below shows output characteristics of the device when using a PCB resistive trace for a low cost solution in replacement for a conventional shunt resistor. The graph shows the linear rise in voltage across the resistor due to the PTC of the material and demonstrates how this rise in resistance value over temperature compensates for the NTC of the device.

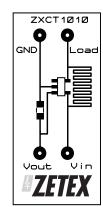
The figure opposite shows a PCB layout suggestion. The resistor section is 25mm x 0.25mm giving approximately 150m Ω using 1oz copper. The data for the normalised graph was obtained using a 1A load current and a 100 Ω output resistor. An electronic version of the PCB layout is available at www.zetex.com/isense



on Temperature Performance



Actual Size

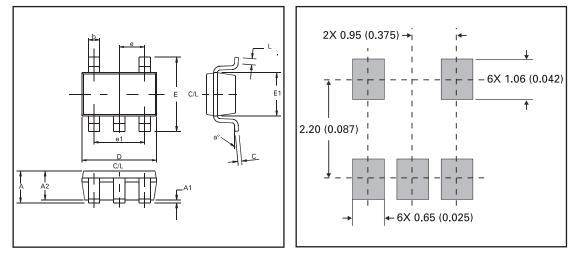


Layout shows area of shunt resistor compared to SOT23-5 package. Not actual size



PACKAGE DIMENSIONS

PAD LAYOUT DETAILS



Controlling dimensions are in millimeters. Approximate conversions are given in inches

PACKAGE DIMENSIONS

DIM	Millim	netres	Inc	hes	DIM	Millimetres		Inches	
	MIN	MAX	MIN	MAX		MIN	MAX	MIN	МАХ
А	0.90	1.45	0.035	0.057	E	2.60	3.00	0.102	0.118
A1	0.00	0.15	0.00	0.006	E1	1.50	1.75	0.059	0.069
A2	0.90	1.3	0.035	0.051	е	0.95	REF	0.037	REF
b	0.35	0.50	0.014	0.020	e1	1.90	REF	0.075	5 REF
С	0.09	0.20	0.0035	0.008	L	0.10	0.60	0.004	0.024
D	2.80	3.00	0.110	0.118	a°	0	10	0	10

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Europe		Americas	Asia Pacific
Zetex plc	Zetex GmbH	Zetex Inc	Zetex (Asia) Ltd
Fields New Road	Streitfeldstraße 19	700 Veterans Memorial Hwy	3701-04 Metroplaza Tower 1
Chadderton Oldham, OL9 8NP	D-81673 München	Hauppauge, NY 11788	Hing Fong Road Kwai Fong
United Kingdom	Germany	USA	Hong Kong
Telephone (44) 161 622 4444	Telefon: (49) 89 45 49 49 0	Telephone: (1) 631 360 2222	Telephone: (852) 26100 611
Fax: (44) 161 622 4446	Fax: (49) 89 45 49 49 49	Fax: (1) 631 360 8222	Fax: (852) 24250 494
hq@zetex.com	europe.sales@zetex.com	usa.sales@zetex.com	asia.sales@zetex.com

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